# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **19.4 dB** and a noise factor of **1.29 dB** at the design frequency **4.00 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

The finalized design will be submitted online in the exam interface on http://rf-opto.etti.tuiasi.ro/, namely:

- 1. Final schematic (all component values will be entered individually on the site + schematic as printscreen)
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- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

There are bonus/penalty points that are added to/subtracted from the final grade, which <u>can</u> be transferred to the lab grade if the final project grade exceeds 10.

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#### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of 23.4 dB and a noise factor of 1.28 dB at the design frequency 2.30 GHz. At the output of the amplifier insert an order 5 bandpass filter with fractional bandwidth of the passband 6% around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **24.6 dB** and a noise factor of **1.25 dB** at the design frequency **1.40 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.1 dB** and a noise factor of **1.31 dB** at the design frequency **3.00 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

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#### **Penalty**

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54<u>143</u>, ATF 35<u>143</u>, ATF 55<u>143</u>, ATF 58<u>143</u> etc.)
- 5. **-1p**, using the NE 71084 transistor

#### **Bonus**

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.3 dB** and a noise factor of **1.29 dB** at the design frequency **2.20 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **5%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54<u>143</u>, ATF 35<u>143</u>, ATF 55<u>143</u>, ATF 58<u>143</u> etc.)
- 5. **-1p**, using the NE 71084 transistor

#### **Bonus**

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.7 dB** and a noise factor of **1.15 dB** at the design frequency **1.50 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
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- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **23.8 dB** and a noise factor of **1.11 dB** at the design frequency **1.50 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **18.3 dB** and a noise factor of **1.35 dB** at the design frequency **4.30 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

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#### **Bonus**

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
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# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **19.9 dB** and a noise factor of **1.31 dB** at the design frequency **3.40 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

#### **Bonus**

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.2 dB** and a noise factor of **1.20 dB** at the design frequency **3.20 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of **<u>complete</u>** data.

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- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of 24.2 dB and a noise factor of 1.22 dB at the design frequency 1.45 GHz. At the output of the amplifier insert an order 5 bandpass filter with fractional bandwidth of the passband 8% around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

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#### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.5 dB** and a noise factor of **1.05 dB** at the design frequency **1.30 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.9 dB** and a noise factor of **1.38 dB** at the design frequency **2.80 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

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- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **23.1 dB** and a noise factor of **1.23 dB** at the design frequency **1.85 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.0 dB** and a noise factor of **1.41 dB** at the design frequency **3.05 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **20.4 dB** and a noise factor of **1.18 dB** at the design frequency **3.35 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **19.8 dB** and a noise factor of **1.44 dB** at the design frequency **4.75 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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## 2. Grading

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#### **Penalty**

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

#### **Bonus**

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **19.2 dB** and a noise factor of **1.23 dB** at the design frequency **3.70 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **6%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
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- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **18.3 dB** and a noise factor of **1.38 dB** at the design frequency **4.25 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **5%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.3 dB** and a noise factor of **1.14 dB** at the design frequency **2.50 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **6%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.3 dB** and a noise factor of **1.14 dB** at the design frequency **2.95 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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#### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **24.9 dB** and a noise factor of **1.24 dB** at the design frequency **1.25 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **5%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

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- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

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#### **Penalty**

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54<u>143</u>, ATF 35<u>143</u>, ATF 55<u>143</u>, ATF 58<u>143</u> etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **18.7 dB** and a noise factor of **1.32 dB** at the design frequency **3.95 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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#### **Penalty**

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

#### **Bonus**

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **17.8 dB** and a noise factor of **1.43 dB** at the design frequency **4.55 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **5%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **24.0 dB** and a noise factor of **1.17 dB** at the design frequency **1.60 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 5. **-1p**, using the NE 71084 transistor

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- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **19.7 dB** and a noise factor of **1.15 dB** at the design frequency **3.55 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of 17.7 dB and a noise factor of 1.34 dB at the design frequency 4.60 GHz. At the output of the amplifier insert an order 5 bandpass filter with fractional bandwidth of the passband 7% around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **19.7 dB** and a noise factor of **1.25 dB** at the design frequency **3.25 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.9 dB** and a noise factor of **1.29 dB** at the design frequency **2.05 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **23.6 dB** and a noise factor of **1.11 dB** at the design frequency **1.25 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **20.2 dB** and a noise factor of **1.37 dB** at the design frequency **4.30 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

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- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.3 dB** and a noise factor of **1.09 dB** at the design frequency **2.15 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

The finalized design will be submitted online in the exam interface on http://rf-opto.etti.tuiasi.ro/, namely:

- 1. Final schematic (all component values will be entered individually on the site + schematic as printscreen)
- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

There are bonus/penalty points that are added to/subtracted from the final grade, which <u>can</u> be transferred to the lab grade if the final project grade exceeds 10.

In establishing the basic grade (to which the bonuses are added) the coincidence (including partial) of the element values is verified, between the individual submissions of all students or with the examples presented at the lab/lectures. Two identical values lead to penalties on both submissions. The more the repeated value is found in individual submissions, the higher the penalty.

#### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

#### **Bonus**

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of 20.3 dB and a noise factor of 1.15 dB at the design frequency 3.00 GHz. At the output of the amplifier insert an order 5 bandpass filter with fractional bandwidth of the passband 5% around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

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- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/**scanned**)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54<u>143</u>, ATF 35<u>143</u>, ATF 55<u>143</u>, ATF 58<u>143</u> etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.9 dB** and a noise factor of **1.34 dB** at the design frequency **3.05 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

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- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

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#### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54<u>143</u>, ATF 35<u>143</u>, ATF 55<u>143</u>, ATF 58<u>143</u> etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of 24.2 dB and a noise factor of 1.33 dB at the design frequency 1.45 GHz. At the output of the amplifier insert an order 5 bandpass filter with fractional bandwidth of the passband 9% around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

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- 1. Final schematic (all component values will be entered individually on the site + schematic as printscreen)
- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

There are bonus/penalty points that are added to/subtracted from the final grade, which <u>can</u> be transferred to the lab grade if the final project grade exceeds 10.

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#### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.6 dB** and a noise factor of **1.29 dB** at the design frequency **2.10 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **5%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

The finalized design will be submitted online in the exam interface on http://rf-opto.etti.tuiasi.ro/, namely:

- 1. Final schematic (all component values will be entered individually on the site + schematic as printscreen)
- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

#### 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

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#### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **19.3 dB** and a noise factor of **1.37 dB** at the design frequency **4.20 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

The finalized design will be submitted online in the exam interface on http://rf-opto.etti.tuiasi.ro/, namely:

- 1. Final schematic (all component values will be entered individually on the site + schematic as printscreen)
- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

There are bonus/penalty points that are added to/subtracted from the final grade, which <u>can</u> be transferred to the lab grade if the final project grade exceeds 10.

In establishing the basic grade (to which the bonuses are added) the coincidence (including partial) of the element values is verified, between the individual submissions of all students or with the examples presented at the lab/lectures. Two identical values lead to penalties on both submissions. The more the repeated value is found in individual submissions, the higher the penalty.

### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **17.3 dB** and a noise factor of **1.20 dB** at the design frequency **4.80 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

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In establishing the basic grade (to which the bonuses are added) the coincidence (including partial) of the element values is verified, between the individual submissions of all students or with the examples presented at the lab/lectures. Two identical values lead to penalties on both submissions. The more the repeated value is found in individual submissions, the higher the penalty.

### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **20.1 dB** and a noise factor of **1.34 dB** at the design frequency **3.20 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **6%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.4 dB** and a noise factor of **1.35 dB** at the design frequency **2.30 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54<u>143</u>, ATF 35<u>143</u>, ATF 55<u>143</u>, ATF 58<u>143</u> etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.5 dB** and a noise factor of **1.15 dB** at the design frequency **1.55 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/**scanned**)
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### **Penalty**

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **20.9 dB** and a noise factor of **1.39 dB** at the design frequency **3.85 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

The finalized design will be submitted online in the exam interface on http://rf-opto.etti.tuiasi.ro/, namely:

- 1. Final schematic (all component values will be entered individually on the site + schematic as printscreen)
- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

There are bonus/penalty points that are added to/subtracted from the final grade, which <u>can</u> be transferred to the lab grade if the final project grade exceeds 10.

In establishing the basic grade (to which the bonuses are added) the coincidence (including partial) of the element values is verified, between the individual submissions of all students or with the examples presented at the lab/lectures. Two identical values lead to penalties on both submissions. The more the repeated value is found in individual submissions, the higher the penalty.

### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.5 dB** and a noise factor of **1.24 dB** at the design frequency **2.80 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

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- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

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### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of 20.3 dB and a noise factor of 1.21 dB at the design frequency 3.85 GHz. At the output of the amplifier insert an order 5 bandpass filter with fractional bandwidth of the passband 5% around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
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### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54<u>143</u>, ATF 35<u>143</u>, ATF 55<u>143</u>, ATF 58<u>143</u> etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.6 dB** and a noise factor of **1.35 dB** at the design frequency **3.55 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

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- 1. Final schematic (all component values will be entered individually on the site + schematic as printscreen)
- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

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### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.2 dB** and a noise factor of **1.41 dB** at the design frequency **3.35 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **6%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

The finalized design will be submitted online in the exam interface on http://rf-opto.etti.tuiasi.ro/, namely:

- 1. Final schematic (all component values will be entered individually on the site + schematic as printscreen)
- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

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### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.8 dB** and a noise factor of **1.29 dB** at the design frequency **2.40 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **5%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

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- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

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### **Penalty**

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **20.0 dB** and a noise factor of **1.37 dB** at the design frequency **3.35 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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### **Penalty**

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.2 dB** and a noise factor of **1.08 dB** at the design frequency **2.00 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/**scanned**)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

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### **Penalty**

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.8 dB** and a noise factor of **1.30 dB** at the design frequency **1.85 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of 23.4 dB and a noise factor of 1.24 dB at the design frequency 2.10 GHz. At the output of the amplifier insert an order 5 bandpass filter with fractional bandwidth of the passband 9% around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of 23.5 dB and a noise factor of 1.07 dB at the design frequency 1.30 GHz. At the output of the amplifier insert an order 5 bandpass filter with fractional bandwidth of the passband 5% around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

Delivery deadline: last day of the semester (02.06.2024, 23:59:59)

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- 1. Final schematic (all component values will be entered individually on the site + schematic as printscreen)
- 2 If you use other transistors than those in the ADS 2003 libraries (e.g. s2p **S-parameter files**), those files <u>must</u> be submitted.
- 3. Results (G,NF as printscreen)
- 4. Handwritten calculus for the matching networks (initial values) and the filter (**!! ''andrei'' factor**: on paper/scanned)
- 5. (Optional) ADS project (\*.zap) + Explanatory document if required to justify the bonus points.

## 2. Grading

The basic grade depends on meeting the requirements in the design data and submission of complete data.

There are bonus/penalty points that are added to/subtracted from the final grade, which <u>can</u> be transferred to the lab grade if the final project grade exceeds 10.

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### **Penalty**

- 1. -2p, lack of the handwritten calculus for the initial lines in the amplifier/filter (i.e. "andrei" factor)
- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **23.1 dB** and a noise factor of **1.12 dB** at the design frequency **2.00 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **19.6 dB** and a noise factor of **1.27 dB** at the design frequency **4.40 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **6%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **24.4 dB** and a noise factor of **1.17 dB** at the design frequency **1.60 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **5%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 2. -2p, usage of lumped elements (L,C) instead of transmission lines in the matching networks or filter
- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.8 dB** and a noise factor of **1.14 dB** at the design frequency **2.15 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **6%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **22.8 dB** and a noise factor of **1.20 dB** at the design frequency **1.40 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **9%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **21.6 dB** and a noise factor of **1.08 dB** at the design frequency **2.00 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 3. -1(2)p, exceeding the submission deadline, until (after) the first week of the exams session (09.06. 2024)
- 4. -2p, using an ATF 34143 family transistor (family: i.e. ATF 54143, ATF 35143, ATF 55143, ATF 58143 etc.)
- 5. **-1p**, using the NE 71084 transistor

- 1. +1p, using two different transistors for the two stages of the amplifier
- 2. +1p, using a different PBF filter schematic than in the example (i.e. coupled lines)
- 3. +2p, upgrading line models from ideal transmission lines to microstrip lines (substrate: alumina 15 mil)
- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **19.6 dB** and a noise factor of **1.25 dB** at the design frequency **3.45 GHz**. At the output of the amplifier insert an order **5** bandpass filter with fractional bandwidth of the passband **7%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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- 5. **-1p**, using the NE 71084 transistor

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- 4. +1(2)p, design (complete design) of transistor bias schematics
- 5. +2p, broadband unconditional stability for the transistors (resistors)

# **MDCR Project**

## 1. Assignment

Design a low-noise multi-stage transistor amplifier required to provide a power gain of **24.4 dB** and a noise factor of **1.15 dB** at the design frequency **1.65 GHz**. At the output of the amplifier insert an order **6** bandpass filter with fractional bandwidth of the passband **8%** around the design frequency. The amplifier must work with a 50 $\Omega$  source and 50 $\Omega$  load.

The matching networks and filter must be implemented with transmission lines (stubs: L7-L8). The use of the transistors we used in lectures and laboratories examples is not permitted (NE 71084, ATF 34143)

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